

## AMENDMENTS TO THE CLAIMS

**1-18 (canceled)**

**19 (currently amended)** A surface acoustic wave filter comprising: where  
a plurality of surface acoustic wave resonators including a comb electrode  
and a grating reflector are coupled on a piezoelectric substrate, and wherein  
a dielectric film is formed on a surface of at least one of the surface  
acoustic wave resonators,  
wherein the dielectric film is not formed on a surface of at least ~~another~~  
one other of the surface acoustic wave resonators, and  
wherein a capacity ratio of the at least one surface acoustic wave resonator  
having the dielectric film is set higher than a capacity ratio ~~that~~ of the at least one other  
surface acoustic wave resonator having no dielectric film.

**20 (currently amended)** The surface acoustic wave filter of claim 19,  
wherein a resonance frequency of the at least one surface acoustic wave  
resonator having the dielectric film is set higher than that of the at least one other surface  
acoustic wave resonator having no dielectric film.

**21 (currently amended)** The surface acoustic wave filter of claim 19,  
wherein a resonance frequency of the at least one surface acoustic wave  
resonator having the dielectric film is set lower than that of the at least one other surface  
acoustic wave resonator having no dielectric film.

**22 (currently amended)** The surface acoustic wave filter of claim 19,  
wherein the surface acoustic wave resonators are coupled in series and in  
parallel to form a ladder type filter structure, and  
wherein the dielectric film is formed on at least one of the surface acoustic  
wave resonators coupled in series or on at least one of the surface acoustic wave  
resonators coupled in parallel.

**23 (previously presented)** The surface acoustic wave filter of claim 19,  
wherein the dielectric film is a silicon dioxide film.

**24 (currently amended)** A surface acoustic wave (SAW) SAW duplexer employing the  
surface acoustic wave filter of claim 19.

**25 (canceled)**

**26 (currently amended)** A~~The~~ surface acoustic wave (SAW) SAW duplexer  
comprising:~~of claim 25~~

a transmission filter;

a reception filter; and

a phase shifter,

wherein each of the transmission filter and reception filter has a ladder  
type structure where surface acoustic wave resonators are coupled in series and in  
parallel,

wherein depending on which side of each pass band requires a steeper  
filter characteristic, a dielectric film is formed on at least one of the surface acoustic wave  
resonators coupled in series or on at least one of the surface acoustic wave resonators  
coupled in parallel,

wherein the SAW duplexer has a frequency allocation where a  
transmission band lies on a low frequency side and a reception band lies on a high  
frequency side,

wherein the transmission filter has a structure where the dielectric film is  
formed on a surface of at least one of the surface acoustic wave resonators coupled in  
series, and

wherein the reception filter has a structure where the dielectric film is  
formed on a surface of at least one of the surface acoustic wave resonators coupled in  
parallel.

**27 (currently amended)** ~~A~~The surface acoustic wave (SAW)SAW duplexer  
comprising:~~of claim 25~~

a transmission filter;

a reception filter; and

a phase shifter,

wherein each of the transmission filter and reception filter has a ladder  
type structure where surface acoustic wave resonators are coupled in series and in  
parallel,

wherein depending on which side of each pass band requires a steeper  
filter characteristic, a dielectric film is formed on at least one of the surface acoustic wave  
resonators coupled in series or on at least one of the surface acoustic wave resonators  
coupled in parallel,

wherein the SAW duplexer has a frequency allocation where a  
transmission band lies on a high frequency side and a reception band lies on a low  
frequency side,

wherein the transmission filter has a structure where the dielectric film is  
formed on a surface of at least one of the surface acoustic wave resonators coupled in  
parallel, and

wherein the reception filter has a structure where the dielectric film is formed on a  
surface of at least one of the surface acoustic wave resonators coupled in series.